

NCE P-Channel Enhancement Mode Power MOSFET

Description

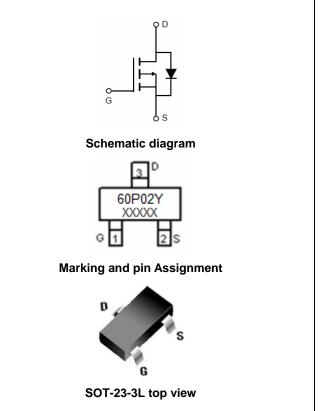
The NCE60P02Y uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for use as a load switch or in PWM applications.

General Features

- $V_{DS} = -60V, I_D = -2A$ $R_{DS(ON)} < 160m\Omega @ V_{GS} = -10V$ $R_{DS(ON)} < 200m\Omega @ V_{GS} = -4.5V$
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Load switch
- PWM application



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
60P02Y	NCE60P02Y	SOT23-3L	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-60	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι _D	-2	А	
Pulsed Drain Current ^(Note 1)	I _{DM}	-8	А	
Maximum Power Dissipation	PD	1.7	W	
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient ^(Note 2)	R _{θJA}	73.5	°C /W
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Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit		
Off Characteristics								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V		





Parameter	Symbol	Condition	Min	Тур	Max	Unit
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.4	-2.0	-2.6	V
Durin Course On Chata Desistence	R _{DS(ON)} -	V _{GS} =-10V, I _D =-2A	-	140	160	mΩ
Drain-Source On-State Resistance		V _{GS} =-4.5V, I _D =-2A	-	160	200	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-2A	-	3	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =-30V,V _{GS} =0V,	-	452	-	PF
Output Capacitance	C _{oss}		-	27.8	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	21.5	-	PF
Switching Characteristics (Note 4)	<u>.</u>					
Turn-on Delay Time	t _{d(on)}	V _{DD} =-30V, I _D =-2A, V _{GS} =-10V,R _G =3Ω	-	40	-	nS
Turn-on Rise Time	tr		-	35	-	nS
Turn-Off Delay Time	t _{d(off)}		-	15	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Qg	V _{DS} =-30,I _D =-2A,	-	9.0	-	nC
Gate-Source Charge	Q _{gs}		-	1.6	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	1.9	-	nC
Drain-Source Diode Characteristics						I.
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2A	-		-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-2	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =- 2A	-	25		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs ^(Note3)	-	31		nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

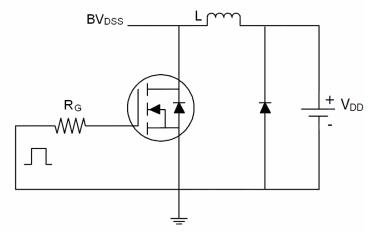
2. Surface Mounted on FR4 Board, t \leq 10 sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

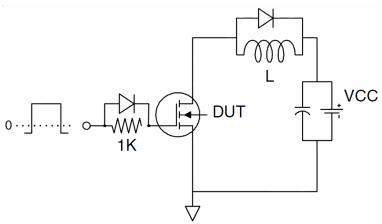
4. Guaranteed by design, not subject to production



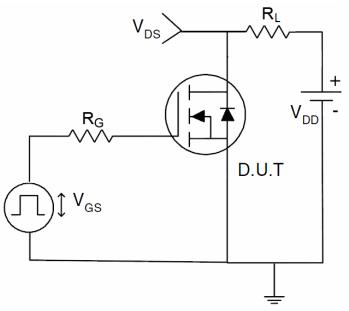
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

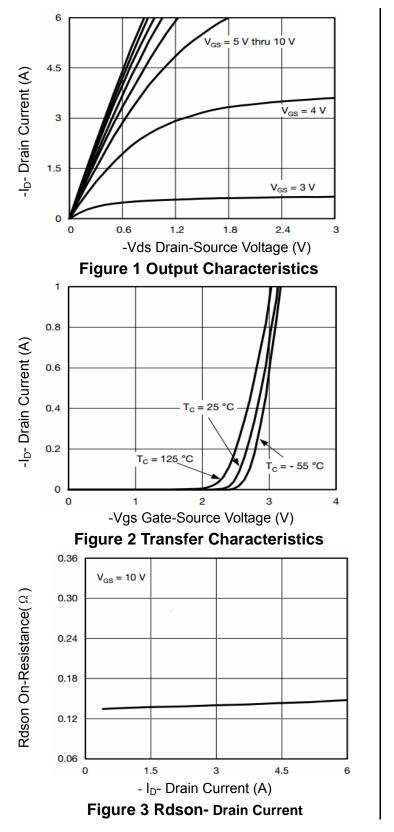


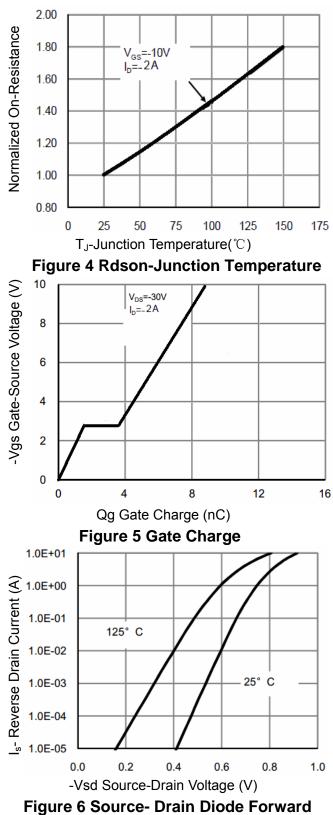
3) Switch Time Test Circuit





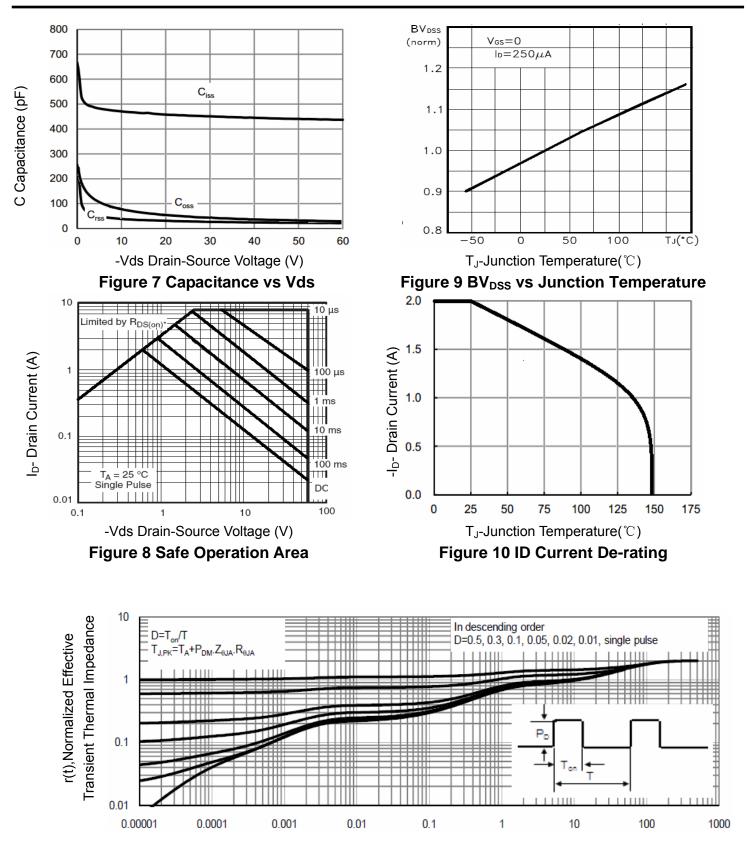
Typical Electrical and Thermal Characteristics (Curves)







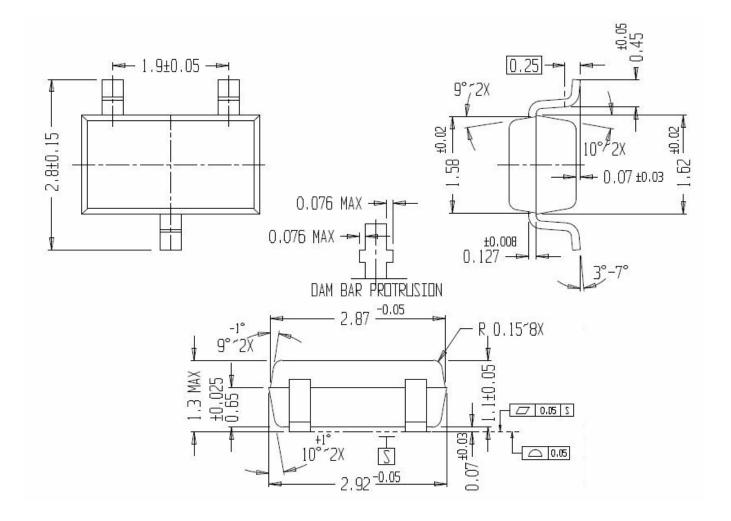
NCE60P02Y



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



SOT23-3L Package Information





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